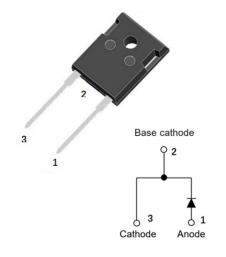
YJD106530NYG4



Silicon Carbide Schottky Diode

V _{RRM}	650V
I _{F (135°C)}	34A
Q _C	92nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-247AC
- Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_c=25[°]C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Device marking code			D106530NYG4
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	v	650
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	650
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	650
Continuous forward current @ T _c =25°C			75
Continuous forward current @ T _c =135°C	IF	A	34
Continuous forward current @ T _c =142°C			30
Non-repetitive peak forward surge current @ $T_c=25^{\circ}C$, tp=10ms, Half Sine Wave	I _{FSM}	A	200
Power Dissipation@ T _c =25°C	5	w	238
Power Dissipation@ T _c =110°C	P _{TOT}		103
i²t Value@ T _c =25°C ,tp=10ms	∫ i²dt	A ² S	200
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175

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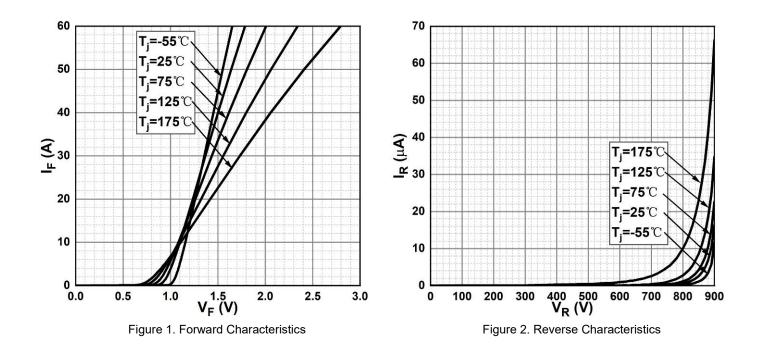
Electrical Characteristics

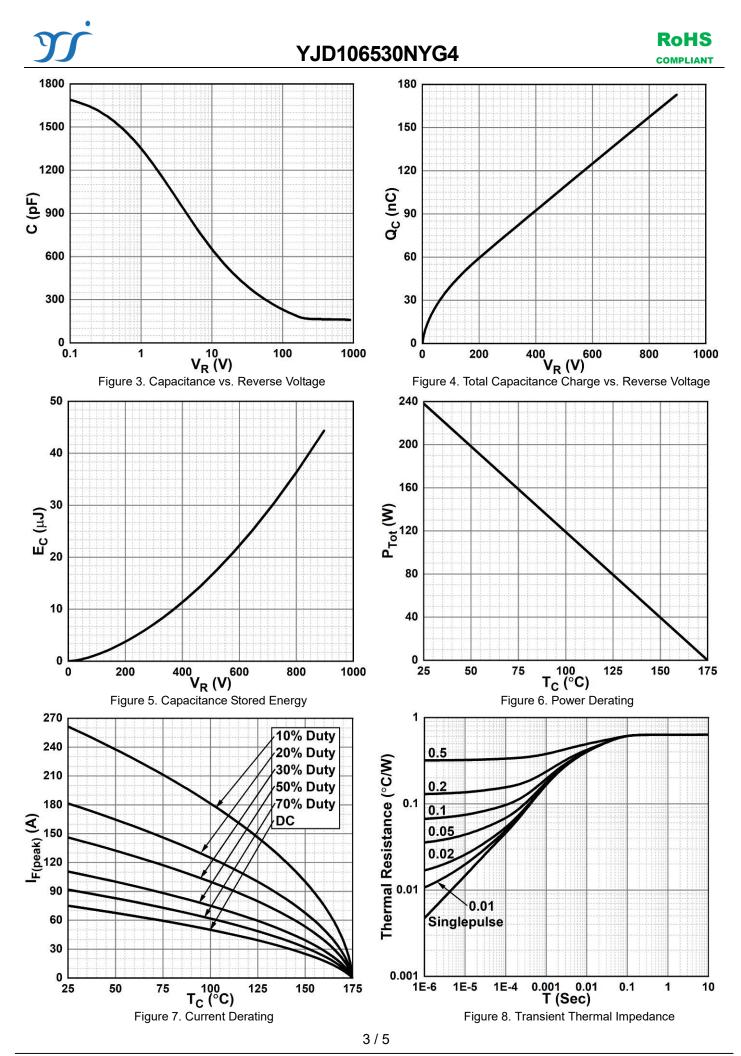
PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drap	V _F	V	I _F =30A, T _j =25°C	1.36	1.58
Forward voltage drop	VF	V	I _F =30A, T _j =175°C	1.75	-
Reverse current		μΑ	V _R =650V, T _j =25°C	0.2	25
Reverse current	I _R		V _R =650V, T _j =175°C	2	-
Total capacitive charge	Qc	nC	$ \begin{array}{l} V_{\text{R}} = 400 \text{V}, \ T_{j} = 25^{\circ}\text{C} \ , \\ Q_{\text{C}} = \hat{J}_{0}^{\ \text{VR}} C(\text{V}) \text{dV} \end{array} $	92	-
			V _R =0V, f=1MHZ	1732	-
Total capacitance	С	pF	V _R =200V, f=1MHZ	171	-
			V _R =400V, f=1MHZ	164	-
Capacitance stored energy	Ec	μJ	V _R =400V	11	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C /W	0.63

■Typical Characteristics



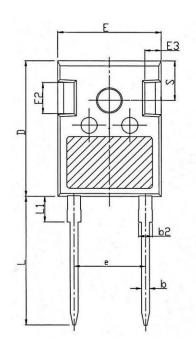


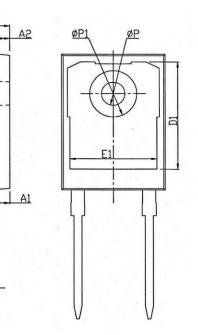
Yangzhou Yangjie Electronic Technology Co., Ltd.



Outline Dimensions

TO-247AC





TO-247AC					
Dim	Min	Max			
А	4.80	5.20			
A1	2.21	2.61			
A2	1.85	2.15			
b	1.11	1.36			
b2	1.91	2.21			
С	0.51	0.75			
D	20.70	21.30			
D1	16.25	16.85			
E	15.50	16.10			
E1	13.00	13.60			
E2	4.80	5.20			
E3	2.30	2.70			
е	10.88BSC				
L	19.62	20.22			
L1	-	4.30			
ΦP	3.40	3.80			
Φ Ρ 1	-	7.30			
S	6.15BSC				

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Disclaimer

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